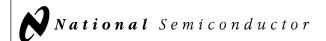
# LM3303,LM3403

LM3303 LM3403 Quad Operational Amplifiers



Literature Number: SNVS022A



# LM3303/LM3403 Quad Operational Amplifiers

# **General Description**

The LM3303 and LM3403 are monolithic quad operational amplifiers consisting of four independent high gain, internally frequency compensated, operational amplifiers designed to operate from a single power supply or dual power supplies over a wide range of voltages. The common mode input range includes the negative supply, thereby eliminating the necessity for external biasing components in many applications.

#### **Features**

- Input common mode voltage range includes ground or negative supply
- Output voltage can swing to ground or negative supply

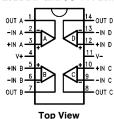
- Four internally compensated operational amplifiers in a single package
- $\blacksquare$  Wide power supply range single supply of 3.0V to 36V dual supply of  $\pm 1.5V$  to  $\pm 18V$
- Class AB output stage for minimal crossover distortion
- Short circuit protected outputs
- High open loop gain 200k
- LM741 operational amplifier type performance

## **Applications**

- Filters
- Voltage controlled oscillators

### **Connection Diagram**

#### 14-Lead DIP and SO-14 Package

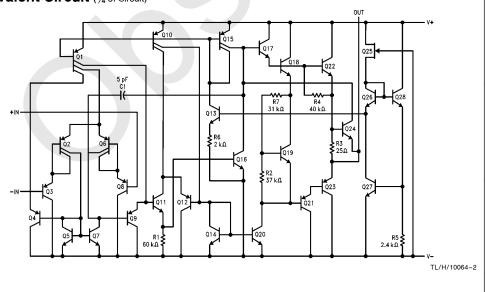


TL/H/10064-1

### **Order Information**

Device	Package	Package
Code	Code	Description
LM3303J	J14A	Ceramic DIP
LM3303N	N14A	Molded DIP
LM3303M	M14A	Molded Surface Mount
LM3403J	J14A	Ceramic DIP
LM3403N	N14A	Molded DIP
LM3403M	M14A	Molded Surface Mount

# Equivalent Circuit (1/4 of Circuit)



### **Absolute Maximum Ratings**

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Storage Temperature Range

-65°C to +175°C -65°C to +150°C Ceramic DIP Molded DIP and SO-14

Operating Temperature Range

 $-40^{\circ}\text{C}$  to  $+85^{\circ}\text{C}$ Industrial (LM3303) Commercial (LM3403) 0°C to +70°C

Lead Temperature

Ceramic DIP (Soldering, 60 sec.) 300°C Molded DIP and SO-14 265°C (Soldering, 10 sec.)

Internal Power Dissipation (Notes 1, 2)

14L-Ceramic DIP 1.36W 14L-Molded DIP 1.04W SO-14 0.93W 36V Supply Voltage between V  $+\,$  and V  $-\,$ Differential Input Voltage (Note 3)  $\pm\,30V$ 

Input Voltage (V-) - 0.3V to V+ESD Tolerance (To Be Determined)

# LM3303 and LM3403

 $\textbf{Electrical Characteristics}\_{T_{A}} = 25^{\circ}\text{C}, V_{CC} = \pm 15\text{V}, \text{unless otherwise specified}$ 

Symbol	Parameter		Conditions		LM3303			LM3403		
Зуппоот			Conditions	Min	Тур	Max	Min	Тур	Max	Units
V <sub>IO</sub>	Input Offset Voltage				2.0	8.0		2.0	8.0	mV
I <sub>IO</sub>	Input Offset Currer	nt			30	75		30	50	nA
I <sub>IB</sub>	Input Bias Current				200	500		200	500	nA
Z <sub>I</sub>	Input Impedance			0.3	1.0		0.3	1.0		$M\Omega$
Icc	Supply Current		$V_0 = 0V, R_L = \infty$		2.8	7.0		2.8	7.0	mA
CMR	Common Mode Re	ejection	$R_S \le 10 \text{ k}\Omega$	70	90		70	90		dB
V <sub>IR</sub>	Input Voltage Range			+ 12V to V -	+ 12.5V to V -		+13V to V-	+ 13.5V to V -		٧
PSRR	Power Supply Rejection Ratio				30	150		30	150	μ٧/٧
los	Output Short Circuit Current (Per Amplifier) (Note 4)			±10	±30	±45	±10	±30	±45	mA
A <sub>VS</sub>	Large Signal Voltage Gain		$V_{O}=\pm 10V,$ $R_{L}\geq 2.0~k\Omega$	20	200		20	200		V/mV
V <sub>OP</sub>	Output Voltage Swing		$R_L = 10  k\Omega$	±12	12.5		±12	+ 13.5		V
			$R_L = 2.0 \text{ k}\Omega$	±10	12		±10	±13		•
TR	Transient Response	Rise Time/ Fall Time	$V_{O} = 50 \text{ mV},$ $A_{V} = 1.0, R_{L} = 10 \text{ k}\Omega$		0.3			0.3		μs
		Overshoot	$V_{O} = 50 \text{ mV},$ $A_{V} = 1.0, R_{L} = 10 \text{ k}\Omega$		5.0			5.0		%
BW	Bandwidth		$V_{O} = 50 \text{ mV},$ $A_{V} = 1.0, R_{L} = 10 \text{ k}\Omega$		1.0			1.0		MHz
SR	Slew Rate		$V_{I} = -10V \text{ to } +10V,$ $A_{V} = 1.0$		0.6			0.6		V/μs

# LM3303 and LM3403 (Continued)

Electrical Characteristics  $T_A=25^{\circ}\text{C},\,V_{CC}=\,\pm\,15\text{V},\,\text{unless otherwise specified}$ 

The following specifications apply for  $-40^{\circ}C \le T_{A} \le +85^{\circ}C$  for the LM3303, and  $0^{\circ}C \le T_{A} \le +70^{\circ}C$  for the LM3403

Symbol	Parameter	Conditions		LM3303		LM3403		}	Units
Symbol	Faiametei	Conditions	Min	Тур	Max	Min	Тур	Max	Office
V <sub>IO</sub>	Input Offset Voltage				10			10	mV
$\Delta V_{IO}/\Delta T$	Input Offset Voltage Temperature Sensitivity			10			10		μV/°C
I <sub>IO</sub>	Input Offset Current				250			200	nA
$\Delta I_{IO}/\Delta T$	Input Offset Current Temperature Sensitivity			50			50		pA/°C
I <sub>IB</sub>	Input Bias Current				1000			800	nA
A <sub>VS</sub>	Large Signal Voltage Gain	$V_O = \pm 10V,$ $R_L \ge 2.0 \text{ k}\Omega$	15			15			V/mV
V <sub>OP</sub>	Output Voltage Swing	$R_L = 2.0 \text{ k}\Omega$	±10			±10			V

# LM3303 and LM3403

**Electrical Characteristics**  $T_A = 25^{\circ}C$ , V + = 5.0V, V - = GND, unless otherwise specified

Symbol	Parameter	Conditions	LM3303			LM3403			Units
Symbol	Farameter		Min	Тур	Max	Min	Тур	Max	Cints
V <sub>IO</sub>	Input Offset Voltage				8.0		2.0	8.0	mV
I <sub>IO</sub>	Input Offset Current				75		30	50	nA
I <sub>IB</sub>	Input Bias Current				500		200	500	nA
Icc	Supply Current			2.5	7.0		2.5	7.0	mA
PSRR	Power Supply Rejection Ratio				150			150	μV/V
A <sub>VS</sub>	Large Signal Voltage Gain	$R_L \ge 2.0  k\Omega$	20	200		20	200		V/mV
V <sub>OP</sub>	Output Voltage Swing	$R_L = 10  k\Omega$	3.3			3.3			
	(Note 5)	$5.0V \leq V + \leq 30V,$ $R_L = 10 \text{ k}\Omega$	(V+) -2.0			(V+) -2.0			V
CS	Channel Separation	1.0 Hz $\leq$ f $\leq$ 20 kHz (Input Referenced)		-120			-120		dB

Note 1:  $T_{J~Max} = 150^{\circ}C$  for the Molded DIP and SO-14, and 175°C for the Ceramic DIP.

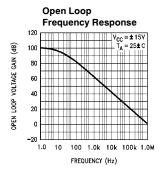
Note 2: Ratings apply to ambient temperature at 25°C. Above this temperature, derate the 14L-Ceramic DIP at 9.1 mW/°C, the 14L-Molded DIP at 8.3 mW/°C, and the SO-14 at 7.5 mW/°C.

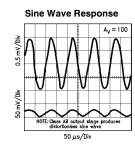
Note 3: For supply voltage less than 30V between V+ and V-, the absolute maximum input voltage is equal to the supply voltage.

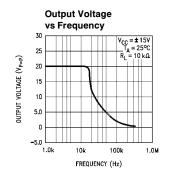
Note 4: Not to exceed maximum package power dissipation.

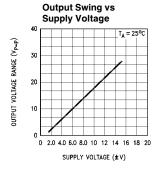
Note 5: Output will swing to ground.

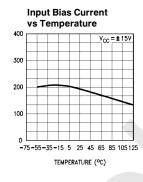
# **Typical Performance Characteristics**

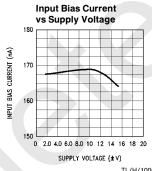






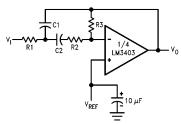






# **Typical Applications**

#### Multiple Feedback Bandpass Filter



TL/H/10064-4

fo = center frequency

 ${\sf BW} = {\sf Bandwidth}$  R in  ${\sf k}\Omega$  C in  $\mu{\sf F}$ 

$$Q=\frac{f_0}{BW}<10$$

$$C1 = C2 = \frac{Q}{3}$$

$$R1 = R2 = 1 R3 = 9Q^2 - 1$$
 Using scaling factors in these expressions.

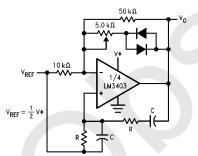
If source impedance is high or varies, filter may be preceded with voltage follower buffer to stabilize filter parameters.

#### Design example:

given: Q = 5, 
$$f_0$$
 = 1 kHz  
Let R1 = R2 = 10 k $\Omega$   
then R3 = 9(5)<sup>2</sup> - 10  
R3 = 215 k $\Omega$ 

$$C=\frac{5}{3}=\,1.6\,nF$$

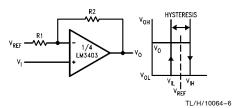
#### Wein Bridge Oscillator



TL/H/10064-5

$$\begin{split} f_0 &= \frac{1}{2\pi RC} \text{for} \, f_0 = 1 \text{ kHz} \\ R &= 16 \text{ k}\Omega \\ C &= 0.01 \text{ } \mu\text{F} \end{split}$$

# Comparator with Hysteresis

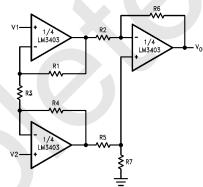


$$V_{IL} = \frac{R1}{R1 + R2}(V_{OL} - V_{REF}) + V_{REF}$$

$$V_{IH} = \frac{R1}{R1 + R2}(V_{OH} - V_{REF}) + V_{REF}$$

$$H = \frac{R1}{R1 \,+\, R2} \left( V_{OH} - V_{OL} \right) \label{eq:hamiltonian}$$

#### **High Impedance Differential Amplifier**



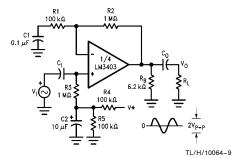
TL/H/10064-7

$$V_{OUT} = C(1 + a + b)(V2 - V1)$$

$$\frac{R2}{R5} \equiv \frac{R6}{R7} \text{ for best CMRR}$$

Gain = 
$$\frac{R6}{R5}$$
  $\left(1 + \frac{2R1}{R3}\right)$  = C (1 + a + b)

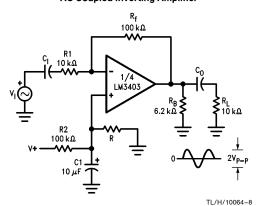
#### **AC Coupled Non-Inverting Amplifier**



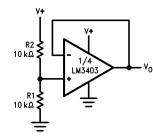
$$A_V = 1 + \frac{R2}{R1}$$

# **Typical Applications** (Continued)

#### **AC Coupled Inverting Amplifier**



#### Voltage Reference



$$V_O = \frac{R1}{R1 + R2} \left( = \frac{V+}{2} \text{ as shown} \right)$$

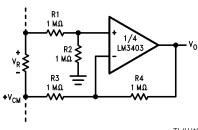
TL/H/10064-10

TL/H/10064-12

$$A_V = \frac{Rf}{Rf}$$

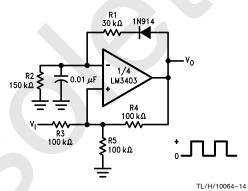
 $A_V = 10$  (as shown)

#### **Ground Referencing a** Differential Input Signal

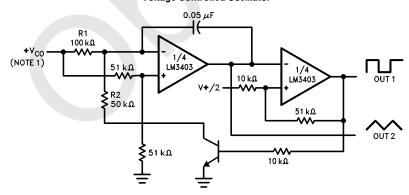


TL/H/10064-11

#### **Pulse Generator**



#### **Voltage Controlled Oscillator**

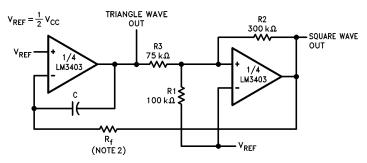


Note 1: Wide Control Voltage Range:

 $0V\,\leq\,V_{\mbox{\footnotesize{CO}}}\,\leq\,2~\mbox{\footnotesize{(V}}\,\pm\,1.5V\mbox{\footnotesize{)}}$ 

# Typical Applications (Continued)

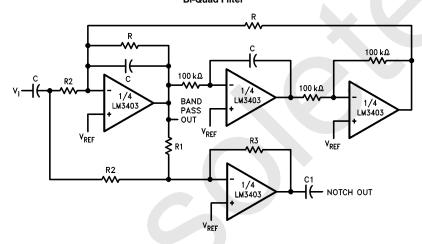
#### **Function Generator**



Note 2:  $f = \frac{R1 + R2}{4CR_fR1}$  if  $R3 = \frac{R2R1}{R2 + R1}$ 

TL/H/10064-13

#### **Bi-Quad Filter**



TL/H/10064-15

 $Q = \frac{BW}{f_0}$ 

where:

 $T_{BP} = Center Frequency Gain$  $T_{N} = Bandpass Notch Gain$ 

$$f_0 = \frac{1}{2\pi RC}, V_{REF} = \frac{1}{2}V_{CC}$$

R1 = QR

$$R2 = \frac{R1}{T_{BP}}$$

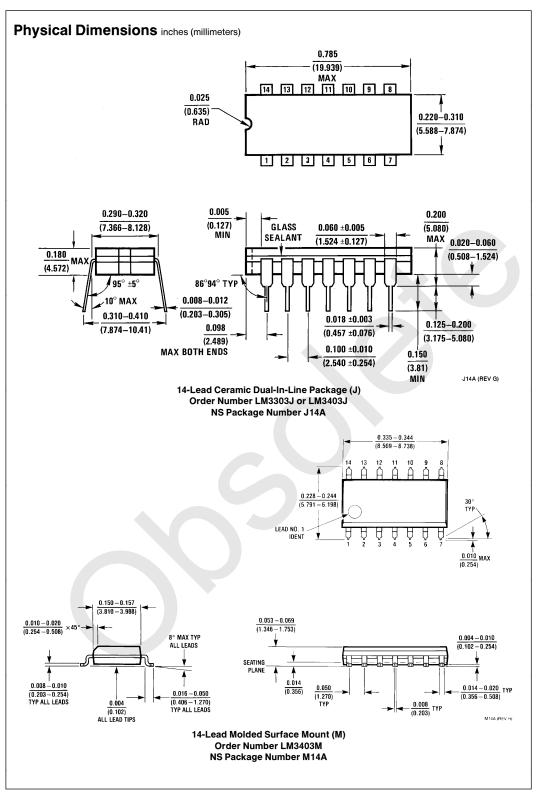
 $R3 = T_N R2$  C1 = 10 C

Example:

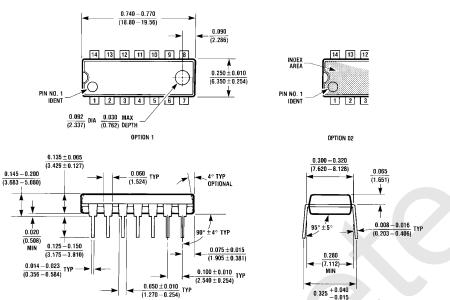
| Example:  $f_0 = 1000 \text{ Hz}$  BW = 100 Hz BW = 100 Hz T<sub>BP</sub> = 1 T<sub>N</sub> = 1 R = 160 kΩ R1 = 1.6 MΩ R2 = 1.6 MΩ C = 0.001 μF

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### Physical Dimensions inches (millimeters) (Continued)



14-Lead Molded Dual-In-Line Package (N) Order Number LM3303N or LM3403N NS Package Number N14A

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N14A (REV F)



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